NSN 5961-01-133-0989

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-133-0989 **Inclosure Material:** Glass or ceramic **Overall Length:** 0.250 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 71.25 regulator voltage and 78.75 regulator voltage **Current Rating Per Characteristic:** 40.00 milliamperes repetitive peak forward current and 0.50 amperes repetitive peak forward current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No